

## Description

### Product Summary

- VDS 20V
- ID 3.2A
- RDS(ON)( at VGS=4.5V) <52mohm
- RDS(ON)( at VGS=2.5V) <68 mohm

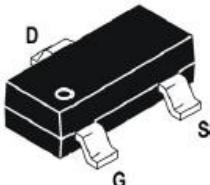
### General Description

- Trench Power LV MOSFET technology
- High Power and current handing capability

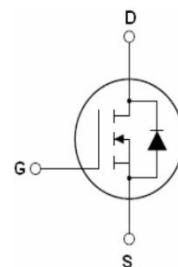
### Applications

- PWM application
- Load switch

### Package



SOT-23



Schematic Diagram

### Absolute Maximum Ratings ( $T_A=25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-source Voltage	VDS	20	V
Gate-source Voltage	VGS	$\pm 12$	V
Drain Current TA=25°C @ Steady State	ID	3.2	A
TA=70°C @ Steady State		2.3	
Pulsed Drain Current A	IDM	12	A
Total Power Dissipation @ TA=25°C	PD	0.84	W
Thermal Resistance Junction-to-Ambient @ Steady State B	R <sub>θJA</sub>	167	°C / W
Junction and Storage Temperature Range	T <sub>J</sub> ,T <sub>STG</sub>	-55~+150	°C



深圳市富满电子集团股份有限公司  
SHEN ZHEN FINE MADE ELECTRONICS GROUP CO., LTD.  
2302P (文件编号: S&CIC1975) N-Channel Trench Power MOSFET

**Electrical Characteristics (T<sub>J</sub>=25°C unless otherwise noted)**

Parameter	Symbol	Conditions	Min	Typ	Max	Units
Static Parameter						
Drain-Source Breakdown Voltage	BVDSS	VGS= 0V, ID=250μA	20			v
Zero Gate Voltage Drain Current	IDSS	VDS=20V, VGS=0V			1	μA
Gate-Body Leakage Current	IGSS	VGS= ±12V, VDS=0V			±100	nA
Gate Threshold Voltage	VGS(th)	VDS= VGS, ID=250μA	0.45	0.65	1.0	v
Static Drain-Source On-Resistance	RDS(ON)	VGS= 4.5V, ID=2.5A		39	52	mΩ
		VGS= 2.5V, ID=2.0A		46	68	
Diode Forward Voltage	VSD	IS=2.5A, VGS=0V			1.2	v
Maximum Continuous Current	Body-Diode IS				3.2	A
Dynamic Parameters						
Input Capacitance	Ciss	VDS=10V, VGS=0V, f=1MHz		182		pF
Output Capacitance	Coss			22		
Reverse Transfer Capacitance	Crss			29		
Switching Parameters						
Total Gate Charge	Qg	VGS=4.5V, VDS=10V, ID=2.5A		3.5		nC
Gate Source Charge	Qgs			0.84		
Gate Drain Charge	Qgd			0.75		
Turn-on Delay Time	tD(on)	VGS=4.5V, VDD=10V, RL=1.5Ω, RGEN=3Ω		7.4		ns
Turn-on Rise Time	tr			56		
Turn-off Delay Time	tD(off)			17		
Turn-off Fall Time	tf			55		

A. Pulse Test: Pulse Width≤300us, Duty cycle ≤2%.

B. Device mounted on FR-4 PCB, 1 inch x 0.85 inch x 0.062 inch.

### Typical Performance Characteristics

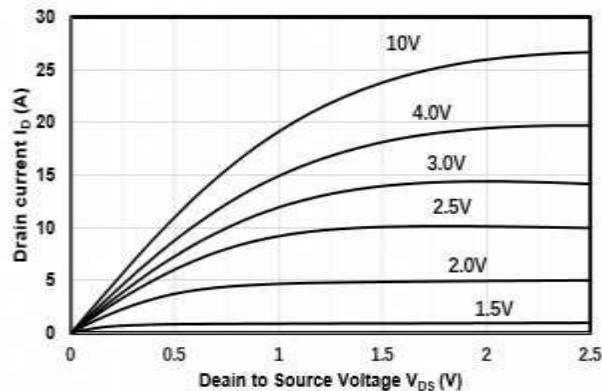


Figure1. Output Characteristics

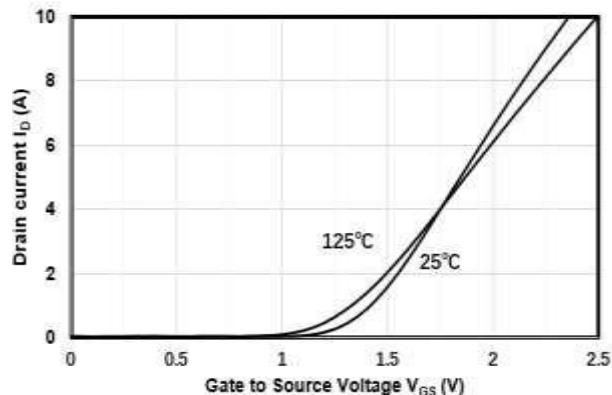


Figure2. Transfer Characteristics

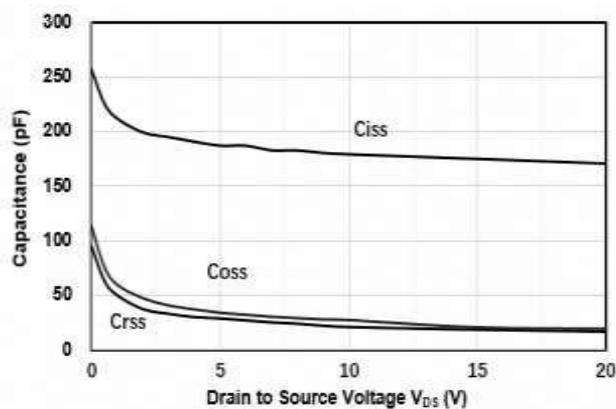


Figure3. Capacitance Characteristics

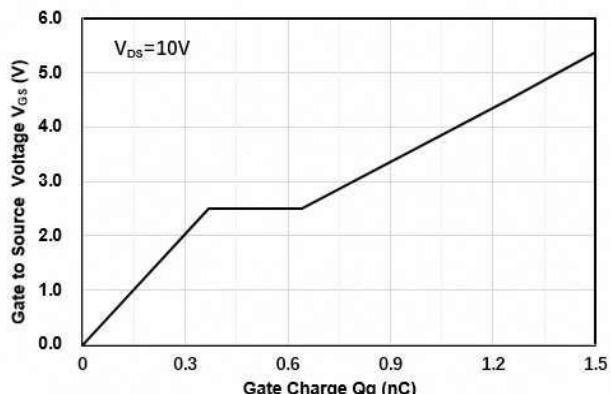


Figure4. Gate Charge

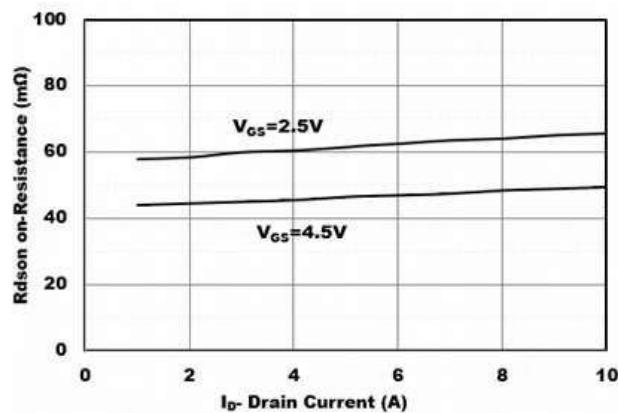


Figure5. Drain-Source on Resistance

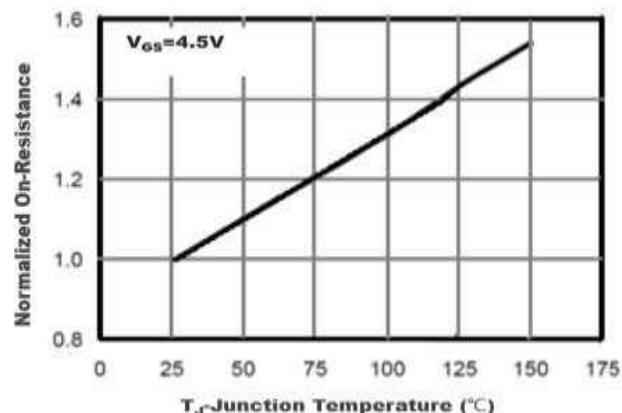


Figure6. Drain-Source on Resistance

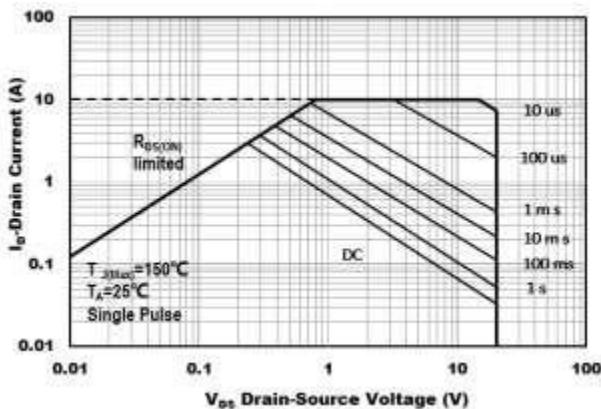


Figure7. Safe Operation Area

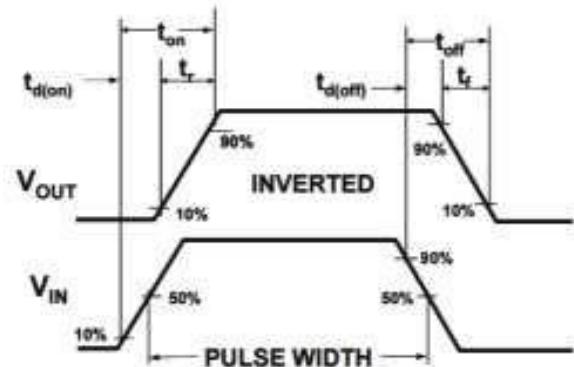
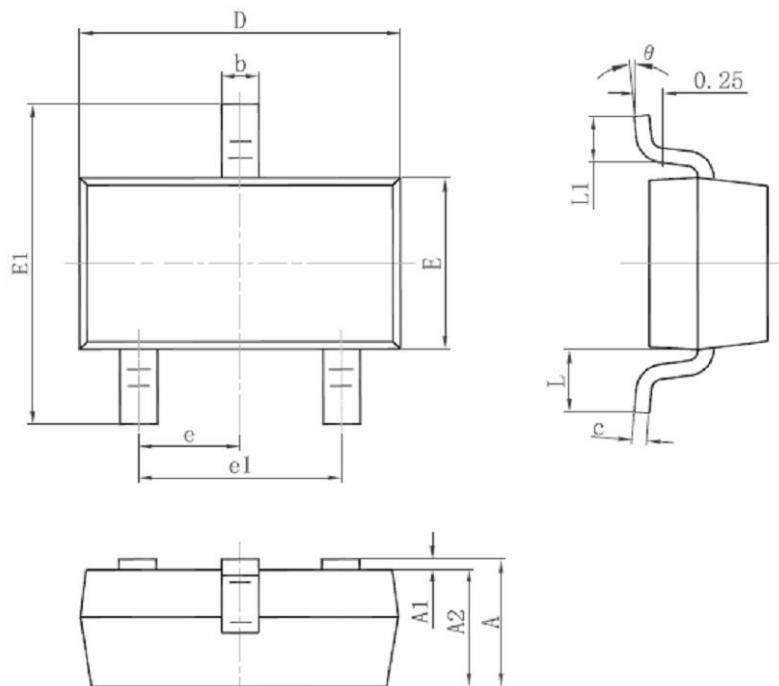


Figure8. Switching wave

**Package Information.**

➤ SOT23-3(小)



符号	毫米		英寸	
	最小	最大	最小	最大
A	0.900	1.150	0.035	0.045
A1	0.000	0.100	0.000	0.004
A2	0.900	1.050	0.035	0.041
b	0.300	0.500	0.012	0.020
c	0.080	0.150	0.003	0.006
D	2.800	3.000	0.110	0.118
E	1.200	1.400	0.047	0.055
E1	2.250	2.550	0.089	0.100
e	0.950 TYP.		0.037 TYP.	
e1	1.800	2.000	0.071	0.079
L	0.550 REF.		0.022 REF.	
L1	0.300	0.500	0.012	0.020
θ	0°	8°	0°	8°

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